

353

Accession number:20123515374722

Title:Optical frequency comb generation using dual-mode injection-locking of quantum-dash mode-locked lasers: Properties and applications

Authors:Sooudi, Ehsan (1); Sygletos, Stylianos (1); Ellis, Andrew D. (1); Huyet, Guillaume (2); McNerney, John G. (1); Lelarge, Francois (4); Merghem, Kamel (5); Rosales, Ricardo (5); Martinez, Anthony (5); Ramdane, Abderrahim (5); Hegarty, Stephen P. (2)

Author affiliation:(1) Department of Physics, University College Cork, Cork, Ireland; (2) Institute of Technology, Cork, Ireland; (3) Tyndall National Institute, Cork, Ireland; (4) Laboratory of Alcatel Lucent Bell Labs, Thales Research and Technology, CEA-LETI, Marcoussis 91460, France; (5) Laboratory for Photonics and Nanostructures, CNRS, Marcoussis 91460, France

Corresponding author:Sooudi, E.(ehsan.sooudi@tyndall.ie)

Source title:IEEE Journal of Quantum Electronics

Abbreviated source title:IEEE J. Quantum Electron.

Volume:48

Issue:10

Issue date:2012

Publication year:2012

Pages:1327-1338

Article number:6249718

Language:English

ISSN:00189197

CODEN:IEJQA7

Document type:Journal article (JA)

Publisher:Institute of Electrical and Electronics Engineers Inc., 445 Hoes Lane / P.O. Box 1331, Piscataway, NJ 08855-1331, United States

Abstract:In this paper, we describe generation and application of wide narrow linewidth optical frequency combs using dual-mode injection-locking of InP quantum-dash mode-locked lasers. First, the dependence of the RF locking-range on the device's absorber voltage is experimentally investigated. Under optimized absorber voltage, a continuous wide RF locking-range of  $\approx 400$  MHz is achievable for lasers with 21 GHz repetition rate. The total RF locking-range of  $\approx 440$  MHz is possible considering locking-range for positive and negative absorber voltages. This wide tuning  $\approx 2\%$  of the repetition rate, a record for a monolithic mode-locked laser, is reported from a two-section device without any additional passive section or extended-cavity for repetition rate tuning. It is shown that the effective RF locking-range in dual-mode injection corresponds to the optical locking-range and repetition rate tuning under CW injection, which is wider when the free-running mode-locking operation is "less stable." The widest comb consists of 35 narrow lines within 10 dB of the peak, spanning  $\approx 0.7$  THz and generating 3.7 ps pulses. Second, we show the first demonstration of multi pump phase-synchronization of two 10 Gb/s DPSK channels in a phase-sensitive amplifier using dual-mode injection-locking technique. The phase-sensitive amplifier based on the "black box" scheme shows more than 7 dB phase-sensitive gain and error free performance for both input channels with 1 dB penalty.  $\copyright$  1965-2012 IEEE.

Number of references:32

Main heading:Lasers

Controlled terms:Laser optics - Natural frequencies - Optical communication - Optical materials

Uncontrolled terms:Mode-locked laser - Optical frequency combs - optical-injection-locking -

Phase-sensitive amplifiers - Quantum dashes

Classification code:717.1 Optical Communication Systems - 741.1 Light/Optics - 741.3 Optical

Devices and Systems - 744.1 Lasers, General

DOI:10.1109/JQE.2012.2210389

Database:Compendex

Compilation and indexing terms, Copyright 2012 Elsevier Inc.